MBRAF1540T3G, NRVBAF1540T3G

Surface Mount Schottky Power Rectifier

This device employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes in surface mount applications where compact size and weight are critical to the system.

Features

- Low Profile Package for Space Constrained Applications
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- 150°C Operating Junction Temperature
- Guard-Ring for Stress Protection
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free and Halide-Free Devices

Mechanical Charactersistics

- Case: Epoxy, Molded, Epoxy Meets UL 94, V-0
- Weight: 95 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Cathode Polarity Band
- Device Meets MSL 1 Requirements
- ESD Ratings: Machine Model = C

Human Body Model = 3B

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	V
Average Rectified Forward Current (At Rated V _R , T _C = 100°C)	lo	1.5	Α
Peak Repetitive Forward Current (At Rated V _R , Square Wave, 100 kHz, T _C = 130°C)	I _{FRM}	3.0	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	40	A
Storage/Operating Case Temperature	T _{stg} , T _C	-55 to +150	°C
Operating Junction Temperature	TJ	-55 to +150	°C
Voltage Rate of Change (Rated V _R , T _J = 25°C)	dv/dt	10,000	V/μs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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SCHOTTKY BARRIER RECTIFIER 1.5 AMPERE 40 VOLTS



SMA-FL CASE 403AA STYLE 6

MARKING DIAGRAM



RAE = Specific Device Code A = Assembly Location

Y = Year WW = Work Week = Pb-Free Package

ORDERING INFORMATION

Devid	е	Package	Shipping [†]
MBRAF154	10T3G	SMA-FL (Pb-Free)	5000 / Tape & Reel
NRVBAF15	540T3G	SMA-FL (Pb-Free)	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance,			°C/W
Junction-to-Lead (Note 1)	$R_{ hetaJL}$	25	
Thermal Resistance,			
Junction-to-Ambient (Note 1)	$R_{ heta JA}$	90	

^{1. 1} inch square pad size (1 x 0.5 inch for each lead) on FR4 board.

ELECTRICAL CHARACTERISTICS

Characteristic		Symbol	Va	lue	Unit
Maximum Instantaneous Forward Voltage (Note 2)		٧ _F	T _J = 25°C	T _J = 125°C	V
see Figure 2	$(i_F = 1.5 A)$ $(i_F = 3.0 A)$		0.46 0.54	0.39 0.54	
Maximum Instantaneous Reverse Current (Note 2)	(IF = 0.0 71)	I _R	T _J = 25°C	T _J = 100°C	mA
see Figure 4	$(V_R = 40 \text{ V})$ $(V_R = 20 \text{ V})$		0.8 0.1	5.7 1.6	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width \leq 250 µs, Duty Cycle \leq 2.0%.

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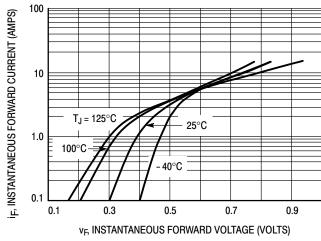


Figure 1. Typical Forward Voltage

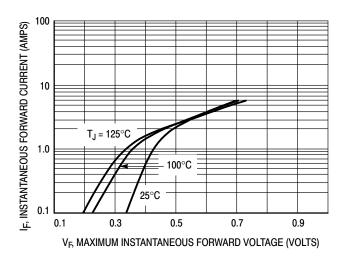


Figure 2. Maximum Forward Voltage

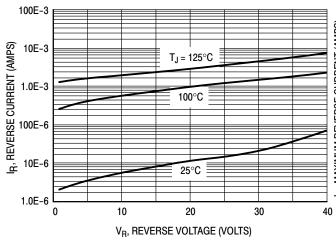


Figure 3. Typical Reverse Current

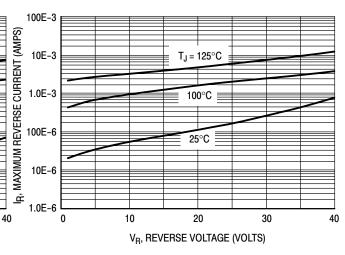


Figure 4. Maximum Reverse Current

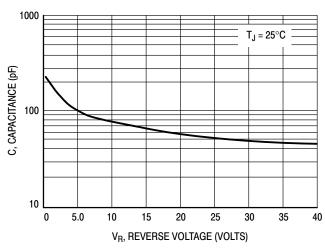


Figure 5. Capacitance

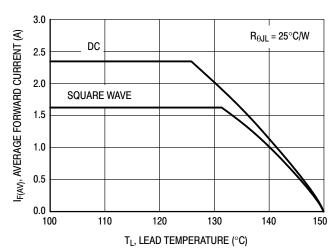


Figure 6. Current Derating

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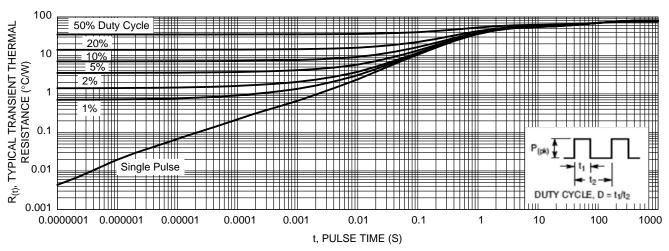


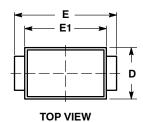
Figure 7. Typical Transient Thermal Response, Junction-to-Ambient

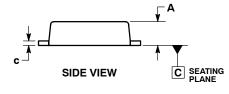


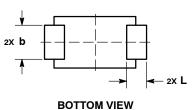


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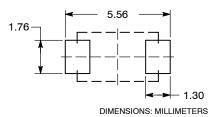


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.90	1.10	
b	1.25	1.65	
С	0.15	0.30	
D	2.40	2.80	
Е	4.80	5.40	
E1	4.00	4.60	
	0.70	1 10	

RECOMMENDED SOLDER FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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